

CMOS 8-Bit Microcontroller

TMP87C814N/F, TMP87CH14N/F, TMP87CK14N/F, TMP87CM14N/F

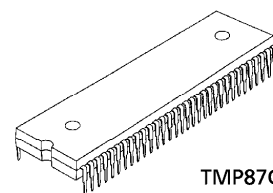
The 87C814/H14/K14/M14 are the high speed and high performance 8-bit single chip microcomputers. These MCU contain 8-bit A/D conversion inputs and a VFT (Vacuum Fluorescent Tube) driver on a chip.

Part No.	ROM	RAM	Package	OTP MCU
TMP87C814N/F	8 K × 8-bit	512 × 8-bit	P-SDIP64-750-1.78	TMP87PM14N/F
TMP87CH14N/F	16 K × 8-bit			
TMP87CK14N/F	24 K × 8-bit	1024 × 8-bit	P-QFP64-1420-1.00A	
TMP87CM14N/F	32 K × 8-bit			

Features

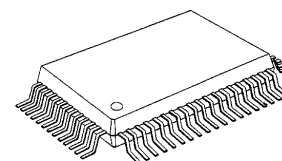
- ◆ 8-bit single chip microcomputer TLCS-870 Series
- ◆ Instruction execution time: 0.5 μ s (at 8 MHz), 122 μ s (at 32.768 kHz)
- ◆ 412 basic instructions
 - Multiplication and Division (8 bits × 8 bits, 16 bits ÷ 8 bits)
 - Bit manipulations (Set/Clear/Complement/Move/Test/Exclusive or)
 - 16-bit data operations
 - 1-byte jump/subroutine-call (Short relative jump/ Vector call)
- ◆ 13 interrupt sources (External: 5, Internal: 8)
 - All sources have independent latches each, and nested interrupt control is available.
 - 3 edge-selectable external interrupts with noise reject
 - High-speed task switching by register bank changeover
- ◆ 8 Input/Output ports (55 pins)
 - Input/Output: 8 ports (55 pins)
- ◆ Two 16-bit Timer/Counters
 - Timer, Event counter, Programmable pulse generator output, Pulse width measurement, External trigger timer, Window modes.
- ◆ Two 8-bit Timer/Counters
 - Timer, Event counter, PWM output, Programmable divider output modes
- ◆ Time Base Timer (Interrupt frequency: 1 Hz to 16 kHz)
- ◆ Divider output function (frequency: 1 kHz to 8 kHz)
- ◆ Watchdog Timer
 - Interrupt source/reset output (programmable)
- ◆ 8-bit Serial Interface: 1 channel
 - With 8 bytes transmit/receive data buffer
 - Internal/external serial clock, and 4/8-bit mode
- ◆ 8-bit successive approximate type A/D converter with sample and hold
 - 8 analog inputs
 - Conversion time: 23 μ s at 8 MHz
- ◆ D/A conversion (Pulse Width Modulation) output
 - 14-bit resolution (1 channel)

P-SDIP64-750-1.78



TMP87C814N
TMP87CH14N
TMP87CK14N
TMP87CM14N
TMP87PM14N

P-QFP64-1420-1.00A



TMP87C814F
TMP87CH14F
TMP87CK14F
TMP87CM14F
TMP87PM14F

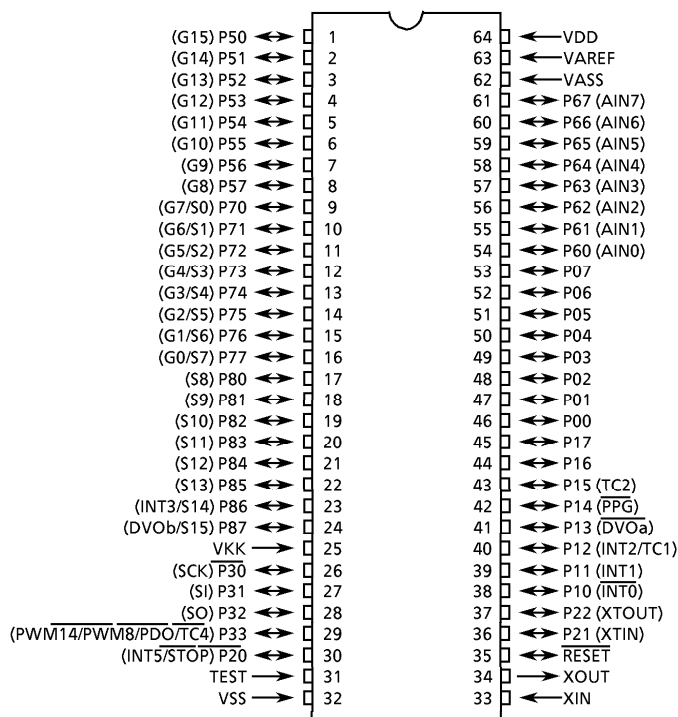
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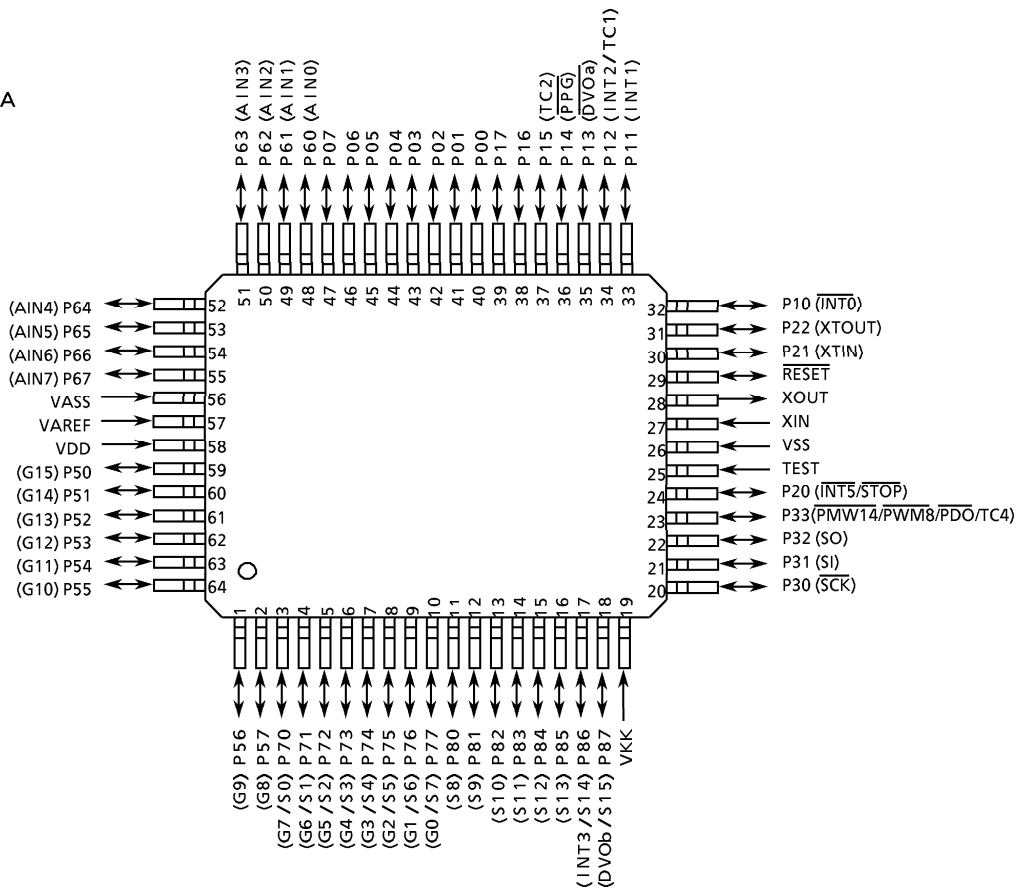
- ◆ Vacuum Fluorescent Tube Driver (automatic display)
 - High breakdown voltage ports (max. 40 V × 24 bits)
- ◆ Dual clock operation
 - Single/Dual-clock mode (option)
- ◆ Five Power saving operating modes
 - STOP mode: Oscillation stops. Battery / Capacitor back-up. Port output hold/High-impedance.
 - SLOW mode: Low power consumption operation using low-frequency clock (32.768 kHz).
 - IDLE1 mode: CPU stops, and Peripherals operate using high-frequency clock. Release by interrupts.
 - IDLE2 mode: CPU stops, and Peripherals operate using high-and low-frequency clock. Release by interrupts.
 - SLEEP mode: CPU stops, and Peripherals operate using low-frequency clock. Release by interrupts.
- ◆ Wide operating voltage: 2.7 to 5.5 V at 32.768 kHz, 4.5 to 5.5 V at 8 MHz / 32.768 kHz
- ◆ Emulation Pod: BM87CM14N0A

Pin Assignments (Top View)

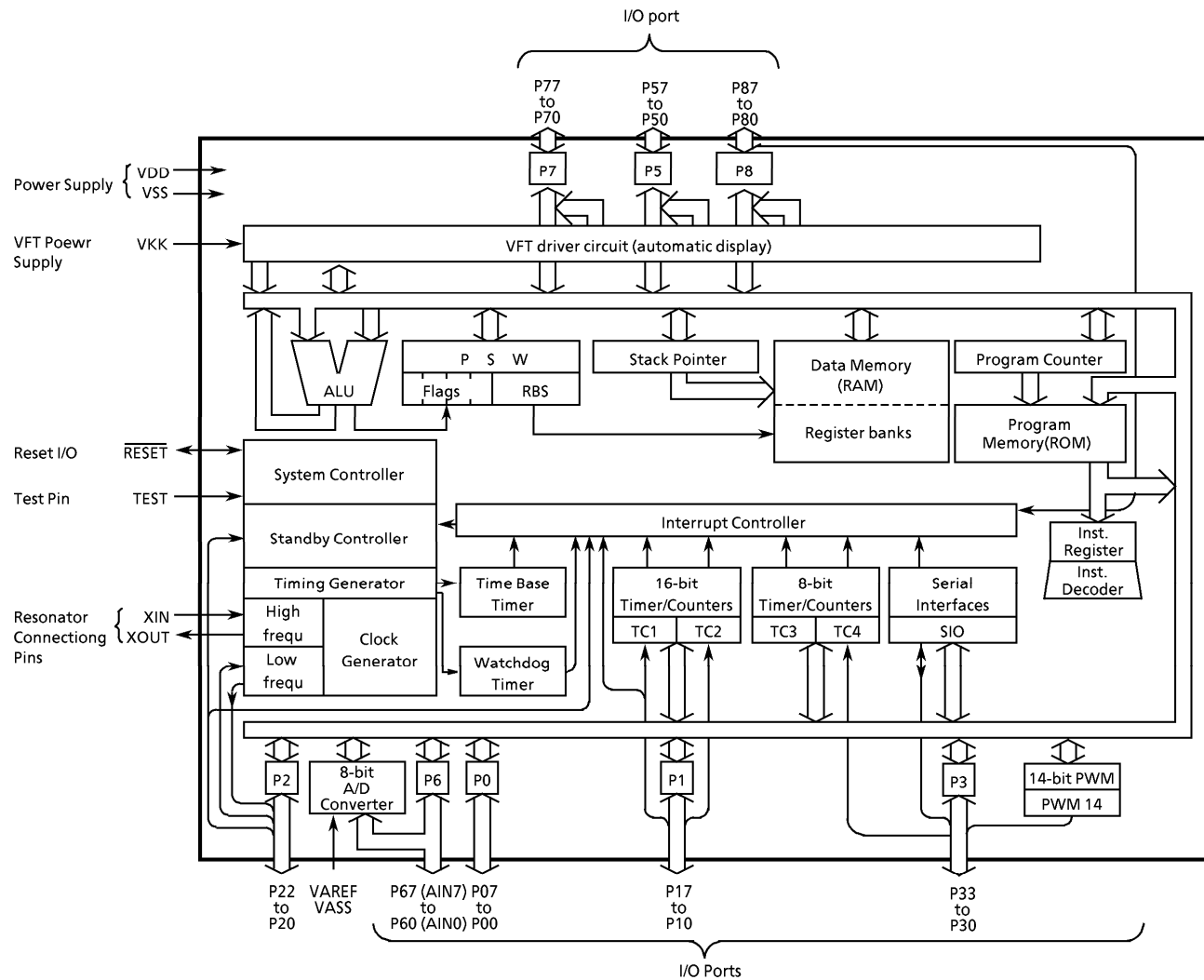
(1) P-SDIP64-750-1.78



(2) P-QFP64-1420-1.00A



Block Diagram



Pin Function

Pin Name	Input / Output	Function	
P07 to P00	I/O	Two 8-bit programmable input/output ports (tri-state). Each bit of these ports can be individually configured as an input or an output under software control. During reset, all bits are configured as inputs. When used as a divider output, the latch must be set to "1".	
P17, P16	I/O		
P15 (TC2)	I/O (Input)		Timer/Counter 2 input
P14 (PPG)	I/O (Output)		Programmable pulse generator output
P13 (DVOa)	I/O (Output)		Divider output a
P12 (INT2 / TC1)	I/O (Input)		External interrupt input 2 or Timer/Counter 1 input
P11 (INT1)			External interrupt input 1
P10 (INT0)			External interrupt input 0
P22 (XTOUT)	I/O (Output)	3-bit input/output port with latch. When used as an input port, the latch must be set to "1".	Resonator connecting pins (32.768 kHz). For inputting external clock, XTIN is used and XTOUT is opened.
P21 (XTIN)	I/O (Input)		External interrupt input 5 or STOP mode release signal input
P20 (INT5 / STOP)			
P33 (PWM14 / PWM8 / PDO / TC4)	I/O (I/O)	4-bit input/output port with latch. When used as an input port, a SIO input/output, a timer/counter input, or an interrupt input, the latch must be set to "1".	14-bit PWM output or 8-bit PWM output or 8-bit programmable divider output or Timer/Counter 4 input
P32 (SO)	I/O (Output)		SIO serial data Output
P31 (SI)	I/O (Input)		SIO serial data Input
P30 (SCK)	I/O (I/O)		SIO serial clock input/output
P57 (G8) to P50 (G15)	I/O (Output)	8-bit high breakdown voltage input/output ports with the latch. When used as a VFT driver output, the latch must be cleared to "0".	VFT digit driver outputs
P67 (AIN7) to P60 (AIN0)	I/O (Input)	8-bit programmable input/output port (tri-state). Each bit of the port can be individually configured as an input or an output under software control.	A/D converter analog inputs
P77 (S7/G0) to P70 (S0 / G7)	I/O (Output)	Two 8-bit high breakdown voltage output ports with the latch. When used as a VFT driver output, the latch must be cleared to "0".	VFT digit/segment driver outputs
P87 (DVOb / S15)	I/O (Output)	Two 8-bit high breakdown voltage output ports with the latch. When used as a VFT driver output, the latch must be cleared to "0".	Divider output b or VFT segment driver output
P86 (INT3 / S14)	I/O (I/O)		External interrupt input 3 or VFT segment driver output
P85 (S13) to P80 (S8)	I/O (Output)		VFT segment output
XIN, XOUT	Input, Output	Resonator connecting pins for high-frequency clock. For inputting external clock, XIN is used and XOUT is opened.	
RESET	I/O	Reset signal input or watchdog timer output/address-trap-reset output/system-clock-reset output.	
TEST	Input	Test pin for out-going test. Be tied to low	
VDD, VSS	Power Supply	+ 5 V, 0 V (GND)	
VKK		VFT driver power supply	
VAREF, VASS		Analog reference voltage inputs (High, Low)	

OPERATIONAL DESCRIPTION

1. CPU CORE FUNCTIONS

The CPU core consists of a CPU, a system clock controller, an interrupt controller, and a watchdog timer. This section provides a description of the CPU core, the program memory (ROM), the data memory (RAM), and the reset circuit.

1.1 Memory Address Map

The TLC8-870 Series is capable of addressing 64K bytes of memory. Figure 1-1 shows the memory address maps of the 87C814/H14/K14/M14. In the TLC8-870 Series, the memory is organized 4 address spaces (ROM, RAM, SFR, and DBR). It uses a memory mapped I/O system, and all I/O registers are mapped in the SFR/DBR address spaces. There are 16 banks of general-purpose registers. The register banks are also assigned to the first 128 bytes of the RAM address space.

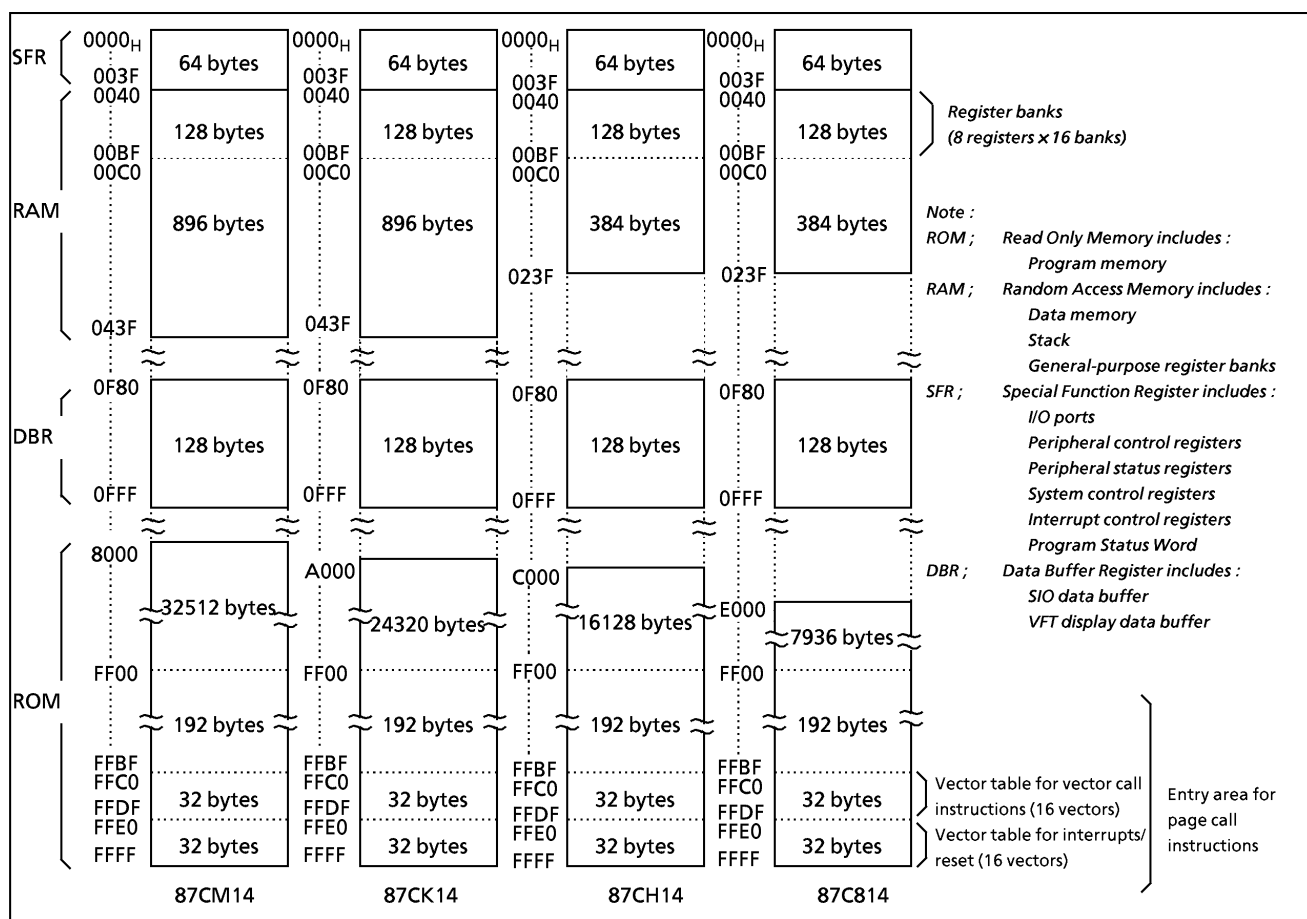


Figure 1-1. Memory Address Maps

Electrical Characteristics

Absolute Maximum Ratings

(V_{SS} = 0 V)

Parameter	Symbol	Pins	Ratings	Unit
Supply Voltage	V _{DD}		– 0.3 to 6.5	V
Input Voltage	V _{IN}		– 0.3 to V _{DD} + 0.3	V
Output Voltage	V _{OUT1}	P0, P1, P2, P3, P6, XOUT, RESET	– 0.3 to V _{DD} + 0.3	V
	V _{OUT2}	Source open drain ports	V _{DD} – 40 to V _{DD} + 0.3	
Output Current (Per 1 pin)	I _{OUT1}	P0, P1, P2, P3, P6	3.2	mA
	I _{OUT2}	P8	– 12	
	I _{OUT3}	P5, P7 (digit outputs)	– 25	
Output Current (Total)	Σ I _{OUT1}	P0, P1, P2, P3, P6	120	mA
	Σ I _{OUT2}	P5, P7, P8	– 120	
Power Dissipation [Topr = 25°C]	PD		600	mW
Soldering Temperature (time)	Tsld		260 (10 s)	°C
Storage Temperature	Tstg		– 55 to 125	°C
Operating Temperature	Topr		– 30 to 70	°C

Note: The absolute maximum ratings are rated values which must not be exceeded during operation, even for an instant. Any one of the ratings must not be exceeded. If any absolute maximum rating is exceeded, a device may break down or its performance may be degraded, causing it to catch fire or explode resulting in injury to the user. Thus, when designing products which include this device, ensure that no absolute maximum rating value will ever be exceeded.

Recommended Operating Conditions

(V_{SS} = 0 V, Topr = – 30 to 70°C)

Parameter	Symbol	Pins	Conditions		Min	Max	Unit
Supply Voltage	V _{DD}		fc = 8 MHz	NORMAL 1, 2 modes	4.5	5.5	V
				IDLE1, 2 modes			
			fs = 32.768 kHz	SLOW mode	2.7		
				SLEEP mode			
				STOP mode	2.0		
Output Voltage	V _{OUT2}	Source open drain ports			V _{DD} – 38	V _{DD}	V
Input High Voltage	V _{IH1}	Except hysteresis input	V _{DD} ≥ 4.5 V		V _{DD} × 0.70	V _{DD}	V
	V _{IH2}	Hysteresis input			V _{DD} × 0.75		
	V _{IH3}		V _{DD} < 4.5 V		V _{DD} × 0.90		
Input Low Voltage	V _{IL1}	Except hysteresis input	V _{DD} ≥ 4.5 V		0	V _{DD} × 0.30	V
	V _{IL2}	Hysteresis input				V _{DD} × 0.25	
	V _{IL3}		V _{DD} < 4.5 V			V _{DD} × 0.10	
Clock Frequency	fc	XIN, XOUT	V _{DD} = 4.5 V to 5.5 V		0.4	8.0	MHz
	fs	XTIN, XTOUT			30.0	34.0	kHz

Note 1: The recommended operating conditions for a device are operating conditions under which it can be guaranteed that the device will operate as specified. If the device is used under operating conditions other than the recommended operating conditions (supply voltage, operating temperature range, specified AC/DC values etc.), malfunction may occur. Thus, when designing products which include this device, ensure that the recommended operating conditions for the device are always adhered to.

Note 2: Clock frequency fc: Supply voltage range is specified in NORMAL 1/2 mode and IDLE 1/2 mode.

D.C. Characteristics

(V_{SS} = 0 V, T_{opr} = -30 to 70°C)

Parameter	Symbol	Pins	Conditions	Min	Typ.	Max	Unit
Hysteresis Voltage	V _{HS}	Hysteresis input		—	0.9	—	V
Input Current	I _{IN1}	TEST	V _{DD} = 5.5 V	—	—	± 2	μA
	I _{IN2}	Open drain ports, Tri-state ports	V _{IN} = 5.5 V / 0 V				
	I _{IN3}	RESET, STOP					
Input Resistance	R _{IN2}	RESET		100	220	450	kΩ
Pull-down Resistance	R _I	Source open drain ports	V _{DD} = 5.5 V, V _{OUT} = 5.5 V	—	200	—	
	R _K		V _{DD} = 5.5 V, V _{KK} = -30 V	—	80	—	
Output Leakage Current	I _{LO1}	Sink open drain ports	V _{DD} = 5.5 V, V _{OUT} = 5.5 V	—	—	2	μA
	I _{LO2}	Source open drain ports	V _{DD} = 5.5 V, V _{OUT} = -32 V	—	—	-2	
	I _{LO3}	Tri-state ports	V _{DD} = 5.5 V, V _{OUT} = 5.5 V / 0 V	—	—	± 2	
Output High Voltage	V _{OH2}	Tri-state ports	V _{DD} = 4.5 V, I _{OH} = -0.7 mA	4.1	—	—	V
	V _{OH3}	P8	V _{DD} = 4.5 V, I _{OH} = -8 mA	2.4	—	—	
Output Low Voltage	V _{OL}	Except XOUT	V _{DD} = 4.5 V, I _{OL} = 1.6 mA	—	—	0.4	V
Output High current	I _{OH}	P5, P7	V _{DD} = 4.5 V, V _{OH} = 2.4 V	—	-20	—	mA
Supply Current in NORMAL 1, 2 modes	I _{DD}		V _{DD} = 5.5 V f _c = 8 MHz	—	10	16	mA
Supply Current in IDLE 1, 2 modes			f _s = 32.768 kHz V _{IN} = 5.3 V / 0.2 V	—	4.5	6	
Supply Current in SLOW mode			V _{DD} = 3.0 V f _s = 32.768 kHz	—	30	60	μA
Supply Current in SLEEP mode			V _{IN} = 2.8 V / 0.2 V	—	15	30	
Supply Current in STOP mode			V _{DD} = 5.5 V V _{IN} = 5.3 V / 0.2 V	—	0.5	10	

Note 1: Typical values show those at T_{opr} = 25°C, V_{DD} = 5 V.Note 2: Input Current I_{IN1}, I_{IN3}; The current through resistor is not included, when the input resistor (pull-up/pull-down) is contained.Note 3: Input Current I_{IN4}; The current when the pull-down register (R_k) is not connected by the mask option.

A/D Conversion Characteristics

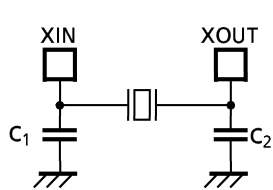
(V_{SS} = 0 V, V_{DD} = 4.5 to 5.5 V, T_{opr} = -30 to 70°C)

Parameter	Symbol	Conditions	Min	Typ.	Max	Unit
Analog Reference Voltage	V _{AREF}	V _{AREF} - V _{ASS} ≥ 2.5 V	V _{DD} - 1.5	—	V _{DD}	V
	V _{ASS}		V _{SS}	—	1.5	
Analog Input Voltage	V _{AIN}		V _{ASS}	—	V _{AREF}	V
Analog Supply Current	I _{REF}	V _{AREF} = 5.5 V, V _{ASS} = 0.0 V	—	0.5	1.0	mA
Nonlinearity Error		V _{DD} = 5.0 V, V _{SS} = 0.0 V V _{AREF} = 5.000 V V _{ASS} = 0.000 V	—	—	± 1	LSB
Zero Point Error			—	—	± 1	
Full Scale Error			—	—	± 1	
Total Error			—	—	± 2	

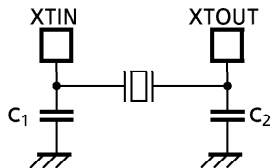
Note: Total errors includes all errors, except quantization error.

A.C. Characteristics		(V _{SS} = 0 V, V _{DD} = 4.5 to 5.5 V, Topr = – 30 to 70°C)					
Parameter	Symbol	Conditions	Min	Typ.	Max	Unit	
Machine Cycle Time	t _{cy}	In NORMAL1, 2 modes	0.5	–	10	μs	
		In IDLE 1, 2 modes					
		In SLOW mode	117.6	–	133.3		
		In SLEEP mode					
High Level Clock Pulse Width	t _{WCH}	For external clock operation (XIN input), fc = 8 MHz	50	–	–	ns	
Low Level Clock Pulse Width	t _{WCL}						
High Level Clock Pulse Width	t _{WSH}	For external clock operation (XTIN input), fs = 32.768 kHz	14.7	–	–	μs	
Low Level Clock Pulse Width	t _{WSL}						

Recommended Oscillating Conditions		(V _{SS} = 0 V, V _{DD} = 4.5 to 5.5 V, Topr = – 30 to 70°C)				
Parameter	Oscillator	Oscillation Frequency	Recommended Oscillator		Recommended Constant	
					C ₁	C ₂
High-frequency Oscillation	Ceramic Resonator	8 MHz	KYOCERA	KBR8.0M	30pF	30pF
		4 MHz	KYOCERA	KBR4.0MS		
			MURATA	CSA 4.00MG		
	Crystal Oscillator	8 MHz	TOYOCOM	210B 8.0000	20pF	20pF
		4 MHz	TOYOCOM	204B 4.0000		
Low-frequency Oscillation	Crystal Oscillator	32.768 KHz	NDK	MX-38T	15pF	15pF



(1) High-frequency Oscillation



(2) Low-frequency Oscillation

Note: An electrical shield by metal shield plate on the IC package should be recommend able in order to prevent the device from the high electric fieldstress applied for continuous reliable operation.